# **BC848** series

# 30 V, 100 mA NPN general-purpose transistors Rev. 07 — 17 November 2009

Product data sheet

# **Product profile**

## 1.1 General description

NPN general-purpose transistors in Surface Mounted Device (SMD) plastic packages.

Table 1. **Product overview** 

Type number	Package	PNP		
	Nexperia	JEITA	JEDEC	complement
BC848B	SOT23	-	TO-236AB	BC858B
BC848W	SOT323	SC-70	-	BC858W

#### 1.2 Features

- General-purpose transistors
- SMD plastic packages

# 1.3 Applications

■ General-purpose switching and amplification

#### 1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	30	V
I <sub>C</sub>	collector current		-	-	100	mA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V};$ $I_{C} = 2 \text{ mA}$				
	BC848B		200	290	450	
	BC848W		110	-	800	



# 2. Pinning information

Table 3. Pinning

	9	
Pin	Description	Simplified outline Symbol
1	base	
2	emitter	3
3	collector	1——
		2 006aaa144

# 3. Ordering information

Table 4. Ordering information

Type number	Package				
	Name	Description	Version		
BC848B	-	plastic surface mounted package; 3 leads	SOT23		
BC848W	SC-70	plastic surface mounted package; 3 leads	SOT323		

# 4. Marking

Table 5. Marking codes

Type number	Marking code <sup>[1]</sup>
BC848B	1K*
BC848W	1M*

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

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#### **Limiting values** 5.

Table 6. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

			,		
Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	30	V
$V_{CEO}$	collector-emitter voltage	open base	-	30	V
$V_{EBO}$	emitter-base voltage	open collector	-	5	V
I <sub>C</sub>	collector current		-	100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
I <sub>BM</sub>	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	<u>[1]</u>		
	SOT23		-	250	mW
	SOT323		-	200	mW
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

# Thermal characteristics

**Product data sheet** 

Table 7. **Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u>			
	SOT23		-	-	500	K/W
	SOT323		-	-	625	K/W

<sup>[1]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

## 7. Characteristics

Table 8. Characteristics

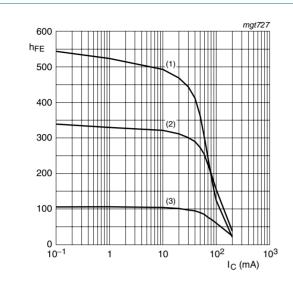
 $T_{amb} = 25 \, ^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_{E} = 0 \text{ A}$		-	-	15	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$		-	-	5	μА
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{E} = 0 \text{ A}$		-	-	100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 10 \mu\text{A}$		-	150	-	
		$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$					
		BC848B		200	290	450	
		BC848W		110	-	800	
V <sub>CEsat</sub> colle	collector-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$		-	90	250	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[1]	-	200	600	mV
$V_{BEsat}$	base-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	[2]	-	700	-	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$	[2]	-	900	-	mV
$V_{BE}$	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	[3]	580	660	700	mV
		I <sub>C</sub> = 10 mA; V <sub>CE</sub> = 5 V	[3]	-	-	770	mV
f <sub>T</sub>	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz		100	-	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz		-	2.5	3	pF
NF	noise figure	$V_{CE} = 5 \text{ V; } I_{C} = 200 \mu\text{A;}$ $R_{S} = 2 k\Omega; f = 1 k\text{Hz;}$ $B = 200 \text{ Hz}$		-	2	10	dB

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

<sup>[2]</sup> V<sub>BEsat</sub> decreases by approximately 1.7 mV/K with increasing temperature.

<sup>[3]</sup>  $V_{BE}$  decreases by approximately 2 mV/K with increasing temperature.



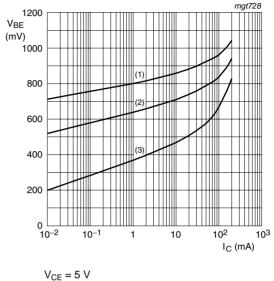
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \,^{\circ}C$$

BC848B: DC current gain as a function of Fig 1. collector current; typical values



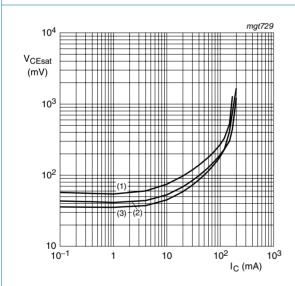
$$V_{CE} = 5 V$$

(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

Fig 2. BC848B: Base-emitter voltage as a function of collector current; typical values



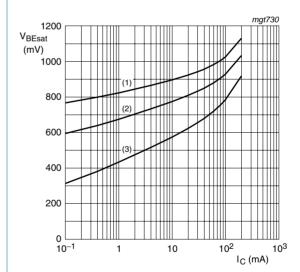
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 150 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = -55 \, ^{\circ}C$$

BC848B: Collector-emitter saturation voltage Fig 3. as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

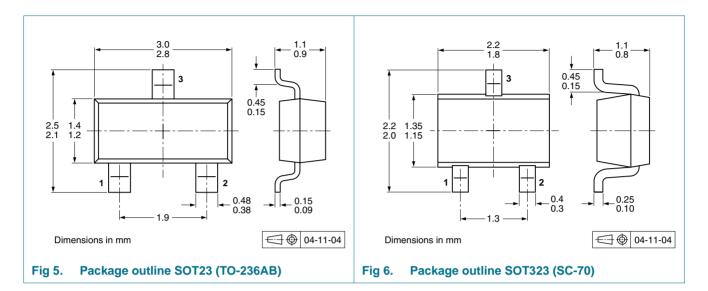
(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3) 
$$T_{amb} = 150 \, ^{\circ}C$$

BC848B: Base-emitter saturation voltage as a Fig 4. function of collector current; typical values

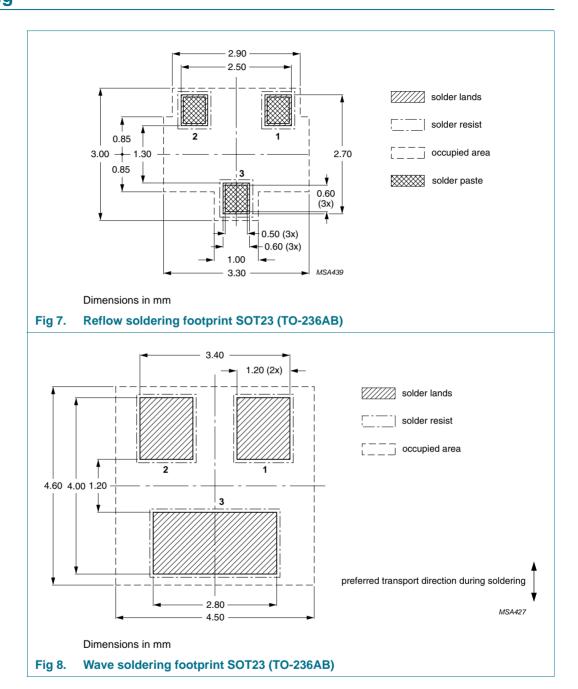
# 8. Package outline

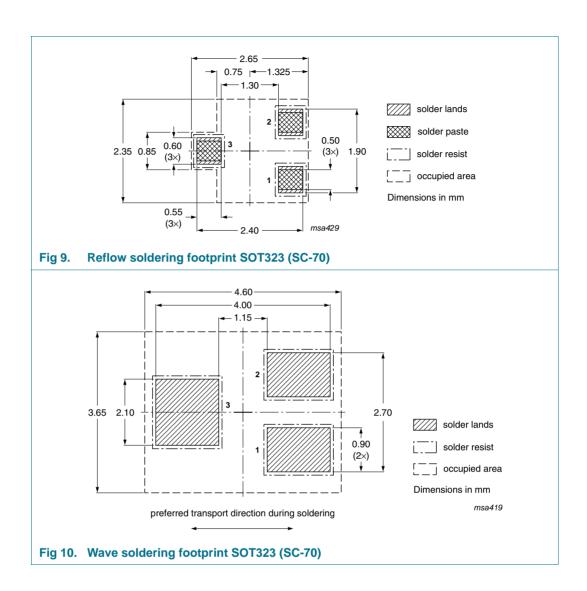


# 9. Packing information

Please refer to packing information on www.nexperia.com.

# 10. Soldering



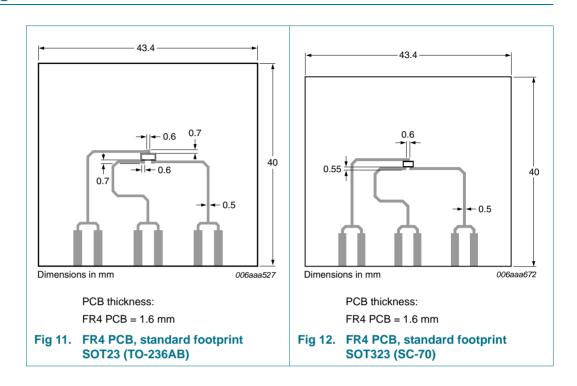


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# 11. Mounting

**Product data sheet** 



# 12. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BC848_SER_7	20091117	Product data sheet	-	BC848_SER_6	
Modifications:	<ul> <li>This data sheet was changed to reflect the new company name NXP Semiconductor including new legal definitions and disclaimers. No changes were made to the technocontent.</li> </ul>				
	<ul> <li>Figure 9 "Reflow</li> </ul>	w soldering footprint SOT32	23 (SC-70)": updated		
	<ul> <li>Figure 10 "Wav</li> </ul>	e soldering footprint SOT3	23 (SC-70)": updated		
BC848_SER_6	20060203	Product data sheet	-	BC846_BC847_ BC848_5 BC846W_BC847W_ BC848W_4	
BC846_BC847_BC848_5	20040206	Product specification	-	BC846_BC847_ BC848_4	
BC846W_BC847W_ BC848W_4	20020204	Product specification	-	BC846W_847W_3	

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Nexperia

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions'
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**BC848** series

## 30 V, 100 mA NPN general-purpose transistors

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